

FEATURES

Collector-Base Voltage
Complement to C945

A733 (PNP)
MARKING: CS
MAXIMUM RATINGS (TA=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-60	V
Collector-Emitter Voltage	V_{CEO}	-50	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current -Continuous	I_C	0.15	A
Collector Power Dissipation	P_C	0.2	W
Junction Temperature	T_J	150	°C
Storage Temperature	T_{stg}	-55 to +150	°C

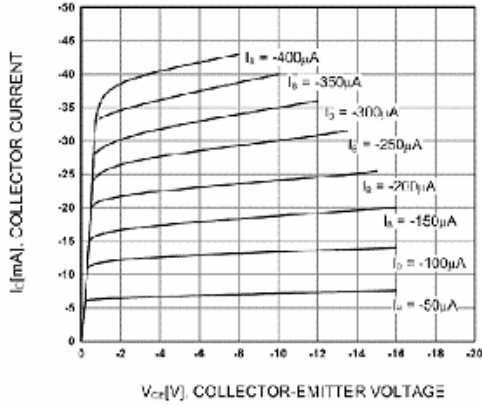

ELECTRICAL CHARACTERISTICS (Tamb=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V_{CBO}	$I_C = -5\mu A, I_E = 0$	-60			V
Collector-emitter breakdown voltage	V_{CEO}	$I_C = -1mA, I_B = 0$	-50			V
Emitter-base breakdown voltage	V_{EBO}	$I_E = -50\mu A, I_C = 0$	-5			V
Collector cut-off current	I_{CBO}	$V_{CB} = -60V, I_E = 0$			-0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = -5V, I_C = 0$			-0.1	μA
DC current gain	h_{FE}	$V_{CE} = -6V, I_C = -1mA$	120		475	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -100mA, I_B = -10mA$		-0.18	-0.3	V
Base-emitter voltage	$V_{BE(on)}$	$V_{CE} = -6V, I_C = -1.0mA$	-0.58	-0.62	-0.68	V
Transition frequency	f_T	$V_{CE} = -6V, I_C = -10mA$	50			MHz
Collector output capacitance	C_{ob}	$V_{CB} = -10V, I_E = 0, f = 1MHz$		4.5	7	pF
Noise figure	NF	$V_{CE} = -6V, I_C = -0.3mA, R_g = 10k, f = 100Hz$		6	20	dB

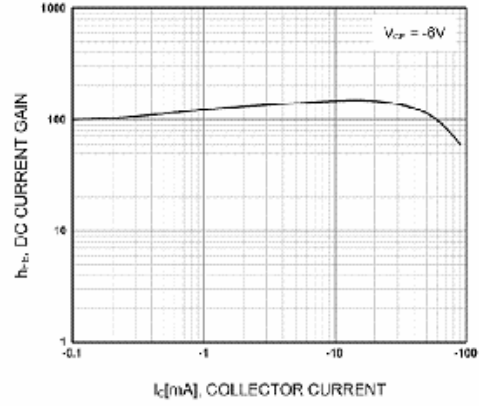
CLASSIFICATION OF h_{FE}

Rank	L	H
Range	120-220	220-475

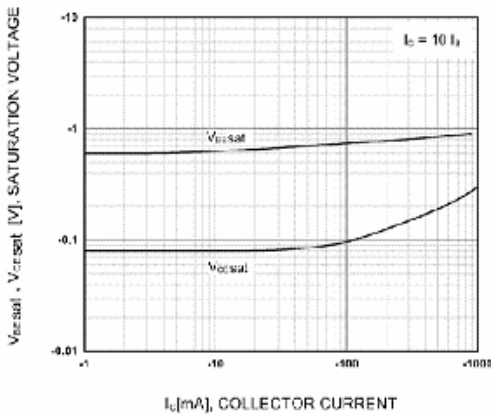
A733 Typical Characteristics



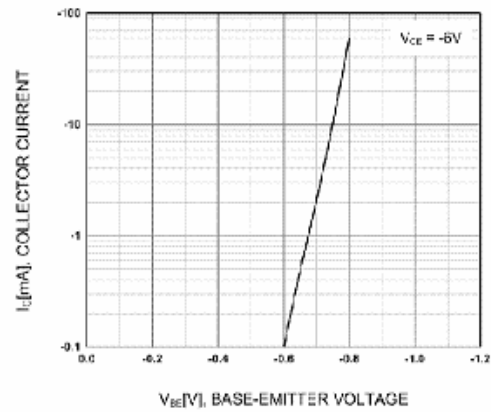
Static Characteristic



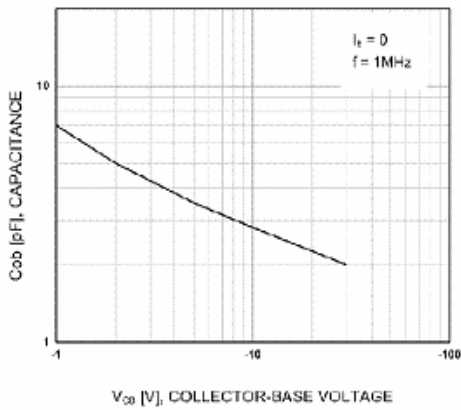
DC current Gain



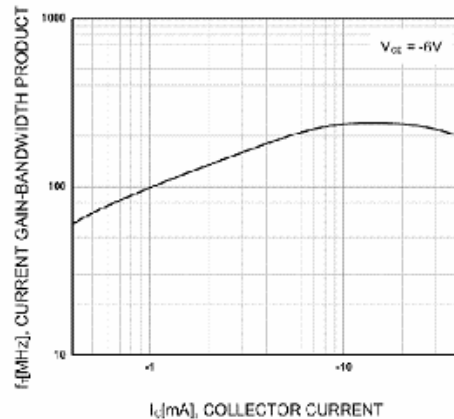
**Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage**



Base-Emitter On Voltage



Collector Output Capacitance



Current Gain Bandwidth Product